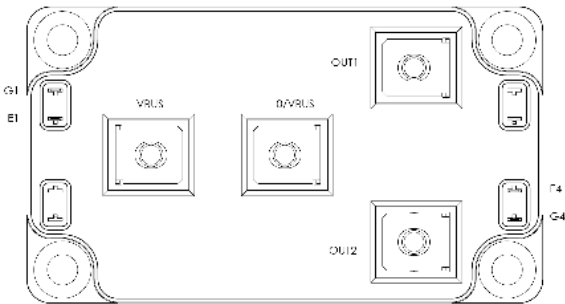
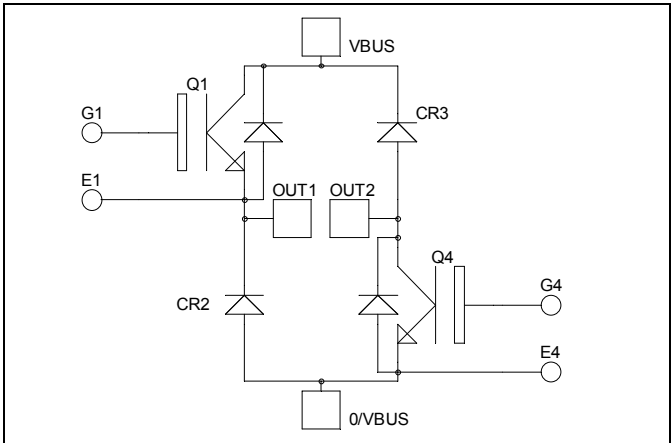


Asymmetrical - Bridge NPT IGBT Power Module

$V_{CES} = 1200V$
 $I_C = 150A @ T_c = 80^\circ C$



Application

- Welding converters
- Switched Mode Power Supplies
- Switched Reluctance Motor Drives

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_c of V_{CEsat}
- Low profile
- RoHS compliant

Absolute maximum ratings

| Symbol | Parameter | Max ratings | Unit |
|-----------|---------------------------------------|---------------------|--------------|
| V_{CES} | Collector - Emitter Breakdown Voltage | 1200 | V |
| I_C | Continuous Collector Current | $T_c = 25^\circ C$ | 200 |
| | | $T_c = 80^\circ C$ | 150 |
| I_{CM} | Pulsed Collector Current | $T_c = 25^\circ C$ | 300 |
| V_{GE} | Gate - Emitter Voltage | ± 20 | V |
| P_D | Maximum Power Dissipation | $T_c = 25^\circ C$ | 961 |
| RBSOA | Reverse Bias Safe Operating Area | $T_j = 150^\circ C$ | 300A @ 1200V |

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|---------------|--------------------------------------|---|---------------------------|-----|-----------|---------------|
| I_{CES} | Zero Gate Voltage Collector Current | $V_{GE} = 0\text{V}$ $V_{CE} = 1200\text{V}$ | $T_j = 25^\circ\text{C}$ | | 350 | μA |
| | | | $T_j = 125^\circ\text{C}$ | | 600 | |
| $V_{CE(sat)}$ | Collector Emitter saturation Voltage | $V_{GE} = 15\text{V}$ $I_C = 150\text{A}$ | $T_j = 25^\circ\text{C}$ | 3.2 | 3.7 | V |
| | | | $T_j = 125^\circ\text{C}$ | 3.9 | | |
| $V_{GE(th)}$ | Gate Threshold Voltage | $V_{GE} = V_{CE}, I_C = 5\text{mA}$ | 4.5 | | 6.5 | V |
| I_{GES} | Gate – Emitter Leakage Current | $V_{GE} = \pm 20\text{V}, V_{CE} = 0\text{V}$ | | | ± 500 | nA |

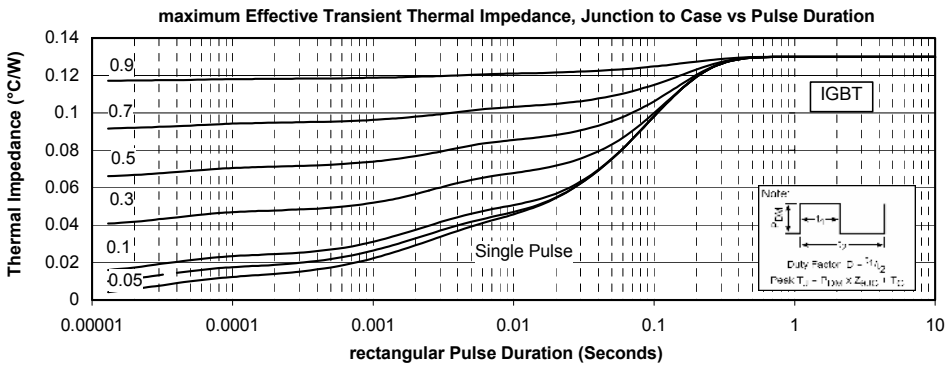
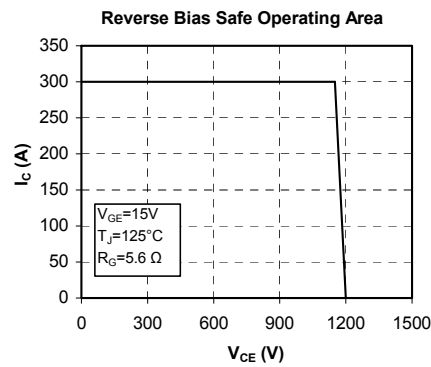
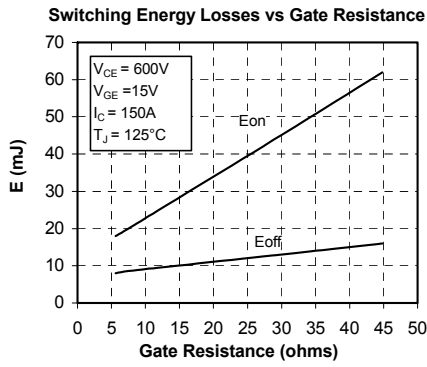
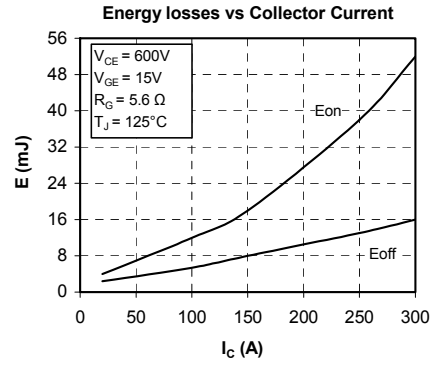
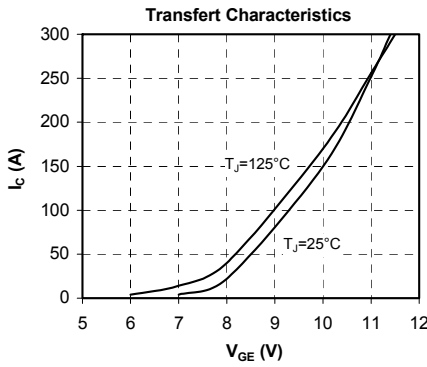
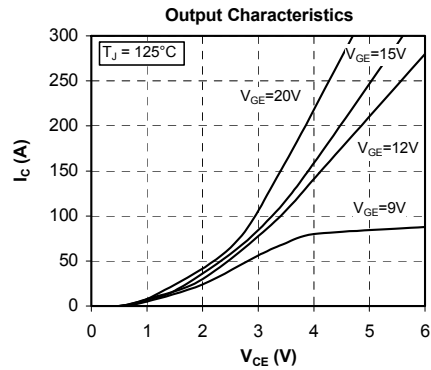
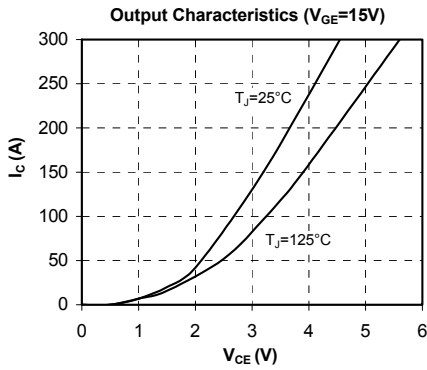
Dynamic Characteristics

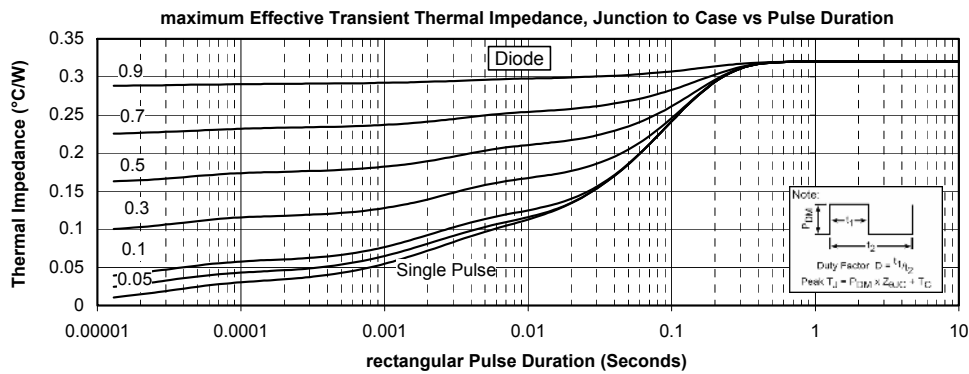
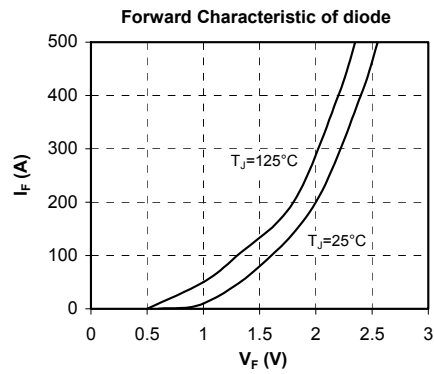
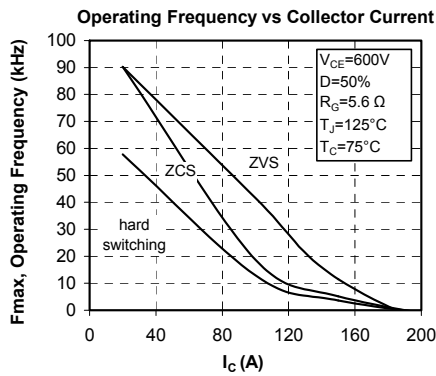
| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|--------------|------------------------------|---|---------------------------|------|-----|------|
| C_{ies} | Input Capacitance | $V_{GE} = 0\text{V}$ $V_{CE} = 25\text{V}$ $f = 1\text{MHz}$ | | 10.2 | | nF |
| C_{oes} | Output Capacitance | | | 1.4 | | |
| C_{res} | Reverse Transfer Capacitance | | | 0.75 | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive Switching (25°C) $V_{GE} = 15\text{V}$ $V_{Bus} = 600\text{V}$ $I_C = 150\text{A}$ $R_G = 5.6\Omega$ | | 120 | | ns |
| T_r | Rise Time | | | 50 | | |
| $T_{d(off)}$ | Turn-off Delay Time | | | 310 | | |
| T_f | Fall Time | | | 20 | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive Switching (125°C) $V_{GE} = 15\text{V}$ $V_{Bus} = 600\text{V}$ $I_C = 150\text{A}$ $R_G = 5.6\Omega$ | | 130 | | ns |
| T_r | Rise Time | | | 60 | | |
| $T_{d(off)}$ | Turn-off Delay Time | | | 360 | | |
| T_f | Fall Time | | | 30 | | |
| E_{on} | Turn-on Switching Energy | $V_{GE} = 15\text{V}$ $V_{Bus} = 600\text{V}$ $I_C = 150\text{A}$ $R_G = 5.6\Omega$ | $T_j = 125^\circ\text{C}$ | 18 | | mJ |
| E_{off} | Turn-off Switching Energy | | $T_j = 125^\circ\text{C}$ | 8 | | |

Diode ratings and characteristics

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|-----------|---|---|---------------------------|------|-----|---------------|
| V_{RRM} | Maximum Peak Repetitive Reverse Voltage | | 1200 | | | V |
| I_{RM} | Maximum Reverse Leakage Current | $V_R = 1200\text{V}$ | $T_j = 25^\circ\text{C}$ | | 350 | μA |
| | | | $T_j = 125^\circ\text{C}$ | | 600 | |
| I_F | DC Forward Current | | | 200 | | A |
| V_F | Diode Forward Voltage | $I_F = 200\text{A}$ | | 2 | 2.5 | V |
| | | $I_F = 400\text{A}$ | | 2.3 | | |
| | | $I_F = 200\text{A}$ | $T_j = 125^\circ\text{C}$ | 1.8 | | |
| t_{rr} | Reverse Recovery Time | $I_F = 200\text{A}$ $V_R = 800\text{V}$ $di/dt = 400\text{A}/\mu\text{s}$ | $T_j = 25^\circ\text{C}$ | 420 | | ns |
| | | | $T_j = 125^\circ\text{C}$ | 520 | | |
| Q_{rr} | Reverse Recovery Charge | | $T_j = 25^\circ\text{C}$ | 2.5 | | μC |
| | | | $T_j = 125^\circ\text{C}$ | 10.7 | | |

Typical Performance Curve





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